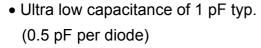
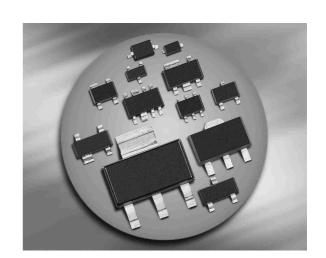


RF ESD Protection Diodes

ESD / transient protection of RF antenna / interfaces or ultra high speed data lines acc. to: IEC61000-4-2 (ESD): ± 20 kV (contact)
IEC61000-4-4 (EFT): 40 A (5/50 ns)
IEC61000-4-5 (surge): 10 A (8/20 μs)



- Low clamping voltage
- Pb-free (ROHS compliant) package



Applications in anti-parallel configuration

 For low RF signal levels without superimposed DC voltage: e.g. GPS, WLAN, Bluetooth

Applications in rail-to-rail configuration

 For high RF signal levels or low RF signal levels with superimposed DC voltage: e.g. HDMI, S-ATA, Gbit Ethernet



ESD1P0RFW

ESD1P0RFS





Туре	Package	Configuration	Marking
ESD1P0RFS	SOT363	2 channels	E6s
ESD1P0RFW	SOT323	1 channel	E6s

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Maximum Ratings at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
ESD contact discharge ¹⁾	V _{ESD}	20	kV
Peak pulse current ($t_p = 8 / 20 \mu s$) ²⁾	I _{pp}	10	Α
Operating temperature range	Top	-55150	°C
Storage temperature	$T_{\rm stq}$	-65150	

Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
Characteristics -		•	•		•
Reverse working voltage ³⁾	V_{RWM}	-	-	70	V
Reverse current	I _R	-	-	100	nA
$V_{R} = 70 \text{ V}$					
Forward clamping voltage ²⁾	V _{FC}				V
$I_{PP} = 3 \text{ A}, t_p = 8/20 \mu\text{s}$		-	4	7	
$I_{PP} = 10 \text{ A}, t_p = 8/20 \mu\text{s}$		-	12	15	
Line capacitance ⁴⁾	C _T				pF
$V_{R} = 0 \text{ V}, f = 1 \text{ MHz}$		-	1	1.5	
$V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$, for Application example 4		-	0.5	0.75	
Series inductance (per diode)	L _S				nH
SOT323		_	1.4	_	
SOT363		_	1.6	_	

 $^{^{1}}V_{\mbox{\footnotesize{ESD}}}$ according to IEC61000-4-2, only valid in anti-parallel or rail-to-rail connection.

Please refer to the application examples.

 $^{^2\}emph{I}_{\mbox{pp}}$ according to IEC61000-4-5, only valid in anti-parallel or rail-to-rail connection.

Please refer to the application examples.

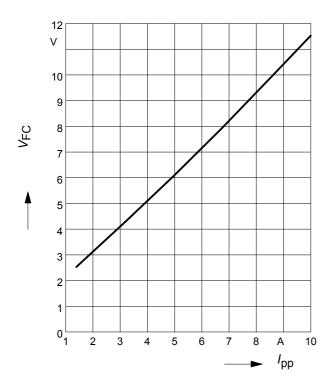
³Only valid in rail-to-rail configuration $V_{CC} \ge V_{RWM}$

⁴Total capacitance line to ground (2 diodes in parallel)



Forward clamping voltage $V_{FC} = f(I_{PP})$

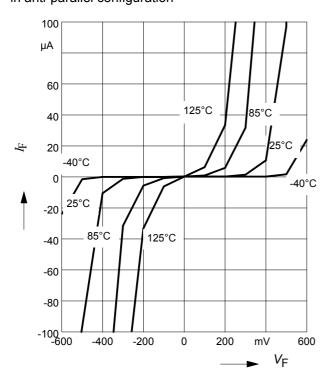
$$t_{\rm p}$$
 = 8 / 20 $\mu {\rm s}$



Forward current $I_F = f(V_F)$

T_A = Parameter

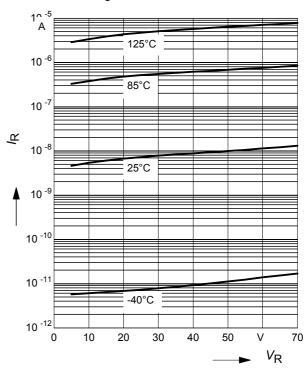
in anti-parallel configuration



Reverse current $I_R = f(V_R)$

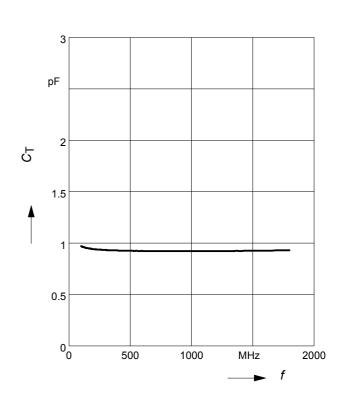
T_{A} = Parameter

in rail-to-rail configuration



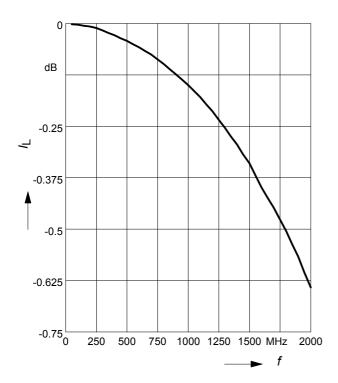
Line capacitance $C_T = f$ (f)

$$V_R = 0 V$$





Insertion loss $|S_{21}|^2 = f(f)$ $V_R = 0$ V, line to ground, $Z = 50 \Omega$

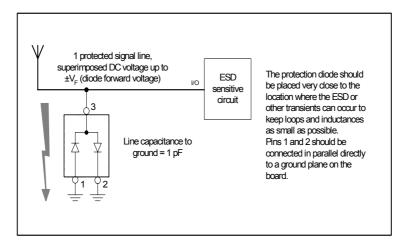


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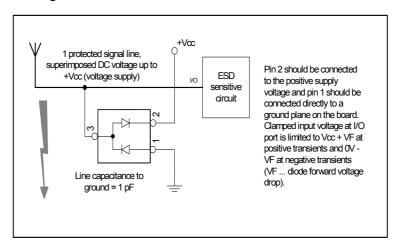
1. Application example ESD1P0RFW

1 channel, anti-parallel configuration



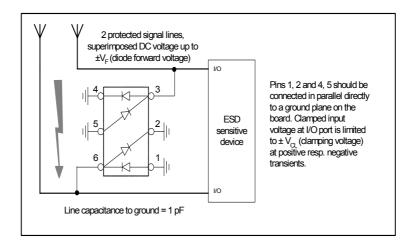
2. Application example ESD1P0RFW

1 channel, rail-to-rail configuration



3. Application example ESD1P0RFS

2 channels, anti-parallel configuration



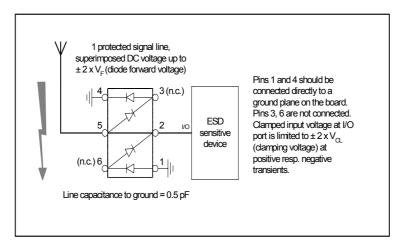
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4. Application example ESD1P0RFS

1 channel, low capacitance anti-parallel configuration



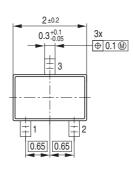
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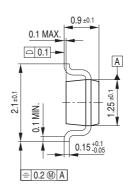




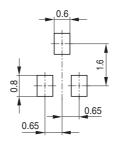
Package Outline



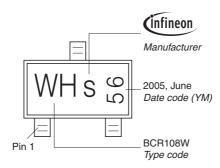




Foot Print

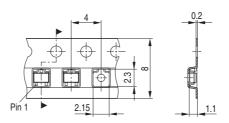


Marking Layout (Example)



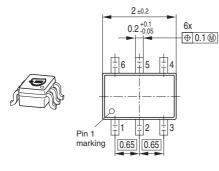
Standard Packing

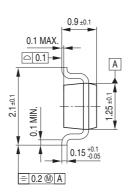
Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



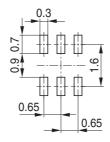


Package Outline



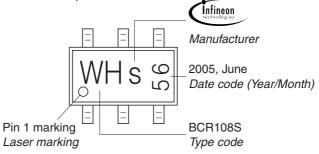


Foot Print



Marking Layout (Example)

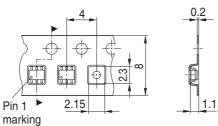
Small variations in positioning of Date code, Type code and Manufacture are possible.



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.



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